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Pressure dependence of the superconducting transition temperature of the filled skutterudite YFe_4P_{12}

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We have studied the pressure dependence of the superconducting transition temperature T_c of the filled skutterudite YFe₄P₁₂ under various quasihydrostatic pressures up to 8 GPa. DC magnetization measurements up to 1.2 GPa in a piston-cylinder cell yields a linear increase of T_c with a positive coefficient $dT_c/dP = 1$ K/GPa. Resistivity measurements up to 8 GPa in a cubic anvil apparatus show that T_c increases to 9.3 K at 8 GPa, but the slope decreases gradually with increasing pressure. Besides the previously reported LaFe₄P₁₂, YFe₄P₁₂ becomes the second filled skutterudite superconductor that exhibits a positive pressure coefficient dT_c/dP in a broad pressure range. The observed large $dT_c/dP > 0$ of YFe₄P₁₂ can be rationalized by our band-structure calculations that show an enhancement of density of states at Fermi energy and the Hopfield parameter under pressure at least up to 8 GPa. On the other hand, similar calculations predict a $dT_c/dP < 0$ for YRu₄P₁₂.

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Filled skutterudites with a general chemical formula RM_4X_{12} (usually R = rare earth or alkaline earth: M = Fe, Ru, Os, Co, Rh, Ir; X = P, As, or Sb) consist of an important material family exhibiting a broad range of intriguing physical phenomena, such as superconductivity, ^{1,2} heavy fermion behavior,² Kondo insulating behavior,³ metalinsulator transition,^{4,5} and various magnetic ordering,⁶ as well as excellent thermoelectric performances. As summarized in Table I, at least 19 filled skutterudites have been reported to be superconducting materials with T_c up to 17 K. Most of these superconductors have been classified as Bardeen-Cooper-Schrieffer (BCS) superconductors, which usually exhibit a negative pressure coefficient of the superconducting transition temperature T_c owing to lattice stiffening under pressure. Based on the available high-pressure studies in the literature, this general rule is followed for most skutterudite superconductors except for LaFe₄P₁₂ (see Ref. 9), which shows a relatively large positive $dT_c/dP = +0.72$ K/GPa up to 1.8 GPa, as shown in Table I. In view of the negative dT_c/dP for M = Ru and Os but positive for M = Fe in the series of LaM₄P₁₂, DeLong and Meisner⁹ have interpreted the pressure effect on T_c for these filled skutterudite superconductors in terms of two competing contributions: (1) a universal decrease of T_c under pressure due to the compression of the skutterudite lattice, and (2) an enhancement of T_c due to a compression of La and its local environment. The latter argument is based on the observations that pure La metal¹⁰ and many La-containing intermetallic superconductors¹¹ exhibit a positive dT_c/dP due to an increase of the density of states (DOS) of 4f bands near the Fermi level under pressure. Taking into account the unique structural characteristic of these filled skutterudites LaM_4P_{12} (M = Fe, Ru, and Os; see inset of Fig. 1), they argued that the latter positive pressure effect becomes effective only where the La atoms inside the $(MP_6)_4$ cages are under compression as in LaFe $_4$ P $_{12}$ (see Ref. 9).

Although the above model provided a simple explanation for the unique positive dT_c/dP of LaFe₄P₁₂, the structural features of the La atoms in the filled skutterudite structure are inside (FeP₆)₄ cages and are well separated (e.g., La-La distance ~ 6.78 Å), 12 which makes the model less convincing. In contrast with the La-containing intermetallic compounds in which the superconductivity is determined mainly by lanthanum (La-La separation $\sim 3.4-3.8 \text{ Å}$), ¹¹ electronic structure calculations¹³ on LaFe₄P₁₂ have suggested that its superconductivity at ambient pressure should be associated largely with the phosphorous sublattice, which forms a strong covalent-bonded P₄ ring and dominates the DOS at the Fermi level $N(E_f)$. In the series of RFe_4P_{12} , YFe₄P₁₂ obtained under high pressure and high temperature (HPHT) conditions has been reported to be superconductive with $T_c^{\text{onset}} \approx 7 \text{ K.}^{14}$ It is well known that Y metal is not superconducting above 6 mK at ambient pressure and becomes superconducting only under pressure P > 11 GPa. Thus, the superconductivity of YFe₄P₁₂ and its variation of T_c with pressure are unlikely determined by direct Y-Y bonding. To shed more light on the unusual positive dT_c/dP of LaFe₄P₁₂. and the mechanism for the superconductivity of RFe₄P₁₂ (R = La, Y), we have investigated the dependence of T_c for YFe₄P₁₂ under quasihydrostatic pressures up to 8 GPa with different high-pressure techniques. DC magnetization measurements up to 1.2 GPa in a piston-cylinder cell show a linear increase of T_c with a large positive coefficient $dT_c/dP =$ 1 K/GPa. Resistivity measurements up to 8 GPa in a cubic multianvil apparatus show that T_c keeps climbing to 9.3 K at 8 GPa, but the slope decreases gradually with increasing pressure. Resistance measurements in a diamond anvil cell (DAC) indicated that T_c is suppressed at higher pressures. Taking into account the structure characteristics revealed by our structural refinement of YFe₄P₁₂, the direct Y-Y bonding is unlikely to contribute the positive pressure effect on T_c .

filled skutterudite supercor	1 0	emperature I_c and its pressur	e coefficients dT_c/dP and $d\ln T_c/dP$	for all known
RM_4X_{12}	$T_{c}\left(\mathbf{K}\right)$	dT_c/dP (K/GPa)	$d \ln T_c / dP \ (10^{-2} \ \text{GPa}^{-1})$	Refs.

RM_4X_{12}	2		$T_c(\mathbf{K})$	dT_c/dP (K/GPa)	$d \ln T_c / dP \ (10^{-2} \ \mathrm{GPa^{-1}})$	Refs.
La	Fe	P	4.1	+0.72	+17.56	9
	Ru	P	7.2	-0.16	-2.22	9
		As	10.3	-0.40	-3.88	45
		Sb	3.58	/	/	46
	Os	P	1.8	-0.095	5.28	9
		As	3.2	/	/	45
		Sb	0.74	/	/	47
	Rh	P	$13.6 \sim 17$	$-(0.3 \sim 0.5)$	$-(2.2 \sim 3.7)$	48
Y	Fe	P	5.6	+1	+17.8	This work
	Ru	P	8.5	/	/	49
	Os	P	3	/	/	50
Pr	Ru	P	2 @14.7 GPa	/	/	51
		As	2.4	/	/	52
		Sb	1.1	-0.21	-19.1	48
	Os	Sb	1.85	/	/	2
La			8.3	/	/	31
Pr	ъ.	G	7.9	/,	/,	
Sr	Pt	Ge	5.4	/	/	
Ba			5.0	/	/	

Instead, the large positive dT_c/dP can be explained by our band-structure calculations that show a dramatic enhancement of $N(E_f)$ and the Hopfield parameter (H-p). Our similar calculations predict a negative dT_c/dP for YRu₄P₁₂, which should be applicable to the LaM₄P₁₂ (T = Ru, Os).

Similar to the previous report by Shirotani *et al.*, ¹⁴ polycrystalline YFe₄P₁₂ samples used in the present study were obtained by sintering a stoichiometric mixture of Y, Fe, and red phosphorous powders at 5 GPa and 1100 °C for 1 h with a Walker-type multianvil module (Rockland Research Co.). All sample preparations were performed in an Ar-filled glove box.

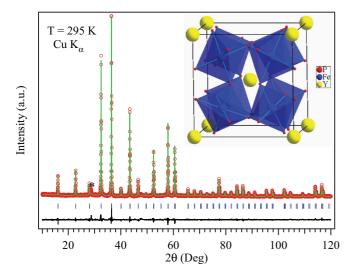


FIG. 1. (Color online) Observed (open circle), calculated (solid line), and difference (bottom) XRD profiles of YFe_4P_{12} obtained under HPHT conditions. The vertical marks are allowed Bragg positions. A trace amount of unknown impurity is indicated by an asterisk (*). Inset displays the unit-cell crystal structure of YFe_4P_{12} .

A hexagonal boron nitride (h-BN) capsule was used directly as the sample container. Details about the sample assembly and procedures for HPHT synthesis can be found elsewhere. ¹⁶ The surface of the as-obtained HP product was polished before measurements of structural and physical properties.

Phase purity of the obtained YFe₄P₁₂ samples was examined by powder x-ray diffraction (XRD) at room temperature with a Philips X'pert diffractometer (Cu K_{α} radiation). The XRD pattern recorded in the 2θ range from 15 to 120° with a step size 0.02° and a dwell time 10 s was analyzed with the Rietveld method by using the FULLPROF program. ¹⁷ Magnetic properties were measured with a commercial superconducting quantum interference device (SQUID) magnetometer (Quantum Design). Electrical resistivity and thermal conductivity were measured with a standard four-probe method and a steady-state method, respectively. A homemade setup was used to measure the thermoelectric power. The magnetization measurements under pressure were performed with a pistoncylinder device fit into the SQUID magnetometer. The sample, together with a piece of Sn as the pressure manometer, was sealed in a Teflon cell filled with a mixture of glycerin and water as the pressure-transmitting medium (PTM). The temperature dependence of resistivity under quasihydrostatic pressures up to 8 GPa was performed in a cubic multianvil apparatus. 18 The preheated pyrophyllite cube was used as gasket and a mixture of glycerin and water as the PTM. Measurements of resistance up to 16 GPa were performed in a DAC. MgO fine powder was used as the insulating layer on a stainless steel (T301) gasket, and h-BN was used as the solid PTM. The pressure applied at room temperature was monitored by the ruby-fluorescence method.

The powder XRD pattern shown in Fig. 1 confirms that the YFe₄ P_{12} sample is nearly single phase with a trace amount of unknown impurity, as indicated by an asterisk (*). To obtain detailed structural information, we have refined the XRD

TABLE II. Atomic coordinates and isotropic thermal factors $B_{\rm iso}$ for YFe₄P₁₂ from powder XRD^a at 295 K; space group: cubic *Im*-3 (No. 204), a = 7.7913(1) Å, V = 472.97(1) Å³, Z = 2.

Atom	Site	x	у	z	$B_{\rm iso}({\rm \AA}^2)$
Y	2a	0	0	0	1.72(9)
Fe	8c	0.25	0.25	0.25	1.63(7)
P	24g	0	0.1472(4)	0.3519(3)	1.51(7)

^aDiscrepancy factors: $R_p = 8.66\%$, $R_{wp} = 11.8\%$, $R_{exp} = 9.60\%$, $\chi^2 = 1.51$, $R_{Bragg} = 4.41\%$.

pattern by taking the structure of LaFe₄P₁₂ as the starting model, ¹² which is defined in the cubic Im-3 (No. 204) space group with Y at 2a (0, 0, 0), Fe at 8c (1/4, 1/4, 1/4), and P at 24g (0, y, z) positions, respectively. The goodness of refinement is illustrated in Fig. 1, and a schematic view of the unit-cell crystal structure is displayed in the inset of Fig. 1. The final atomic positions after the Rietveld refinement are listed in Table II. Selected bond lengths and angles of YFe₄P₁₂ are compared with those of LaFe₄P₁₂ in Table III. The obtained cubic lattice constant a = 7.7913(1) Å is in excellent agreement with that reported by Shirotani et al. ¹⁴ of a = 7.7896(1) Å for YFe₄P₁₂.

It should be noted that no structural refinement has been performed for the lanthanide RFe_4P_{12} (R = Dy, ..., Lu, and Y) except for $R = Yb^{19}$ as far as we know. The structural refinement may provide an important clue to understand the essential role of high-pressure synthesis in stabilizing the filled skutterudite structure for the smaller lanthanides. As a general observation, under ambient pressure the pnictogen's coordination (y, z) in most unfilled binary skutterudites is located below the Oftedal line, y + z = 1/2 in the y versus z plot, whereas that of filled skutterudites is located above the Oftedal line.²⁰ High-pressure synthesis has been shown to be an effective approach in order to fill the binary skutterudites below the Oftedal line.^{21,22} The obtained Phosphorus coordination (0.1472, 0.3519) in Table II is located slightly below the Oftedal line, which can thus explain why a moderate pressure is required in order to stabilize the filled skutterudite structure for YFe₄P₁₂. To further verify this argument, systematic structural refinements on other heavy lanthanides RFe₄P₁₂ are highly

As shown in Table III, replacement of smaller Y for La results in negligible modifications for the (FeP₃)₄ framework in terms of the P-Fe-P and Fe-P-Fe bond angles as well as the Fe-P bond length. The reductions of *R*-P and *R*-Fe interatomic distances, i.e., 0.04 Å and 0.017 Å, respectively,

TABLE III. Comparison of the bond lengths (Å) and angles (°) between YFe_4P_{12} and LaFe_4P_{12}.

	YFe ₄ P ₁₂	LaFe ₄ P ₁₂ (Ref. 12)		
Y-P	2.972(2) (×12)	La-P	3.012 (×12)	
Y-Fe	$3.374(2) (\times 8)$	La-Fe	3.391 (×8)	
Fe-P	$2.251(2)(\times 6)$	Fe-P	$2.259 (\times 6)$	
P-Fe-P	97.1(1)	P-Fe-P	97.9	
P-Fe-P	82.9(1)	P-Fe-P	82.1	
Fe-P-Fe	119.86(5)	Fe-P-Fe	120.1	

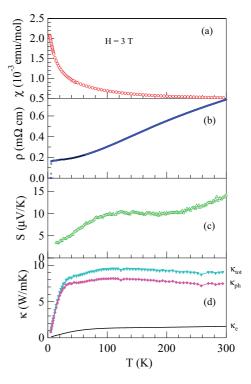


FIG. 2. (Color online) Temperature dependence of the (a) magnetic susceptibility $\chi(T)$ measured under H=3 T after ZFC, (b) resistivity $\rho(T)$, (c) thermopower S(T), and (d) thermal conductivity $\kappa(T)$ in a wide temperature range (2–300 K).

from LaFe₄P₁₂ to YFe₄P₁₂, are much smaller relative to the ionic-radius change between La³⁺ and Y³⁺, i.e., 0.141 Å in a hard-sphere model. In addition, the observed Y-P distance of 2.972(2) Å in YFe₄P₁₂ is longer than that of 2.8266 Å in YP²³ and of 2.945 Å in YP₅ (see Ref. 24). These observations thus indicated that the Y ions in YFe₄P₁₂ are loosely bonded to the (FeP₃)₄ cages in comparison with La in LaFe₄P₁₂. In other words, YFe₄P₁₂ could be more compressible than LaFe₄P₁₂.

Before we move on to the pressure effect on the superconductivity of YFe₄P₁₂, we first describe the physical properties of its normal state. Figure 2 shows the temperature dependences of (a) magnetic susceptibility $\chi(T)$, (b) electrical resistivity $\rho(T)$, (c) thermoelectric power S(T), and (d) thermal conductivity $\kappa(T)$ in the temperature range 2-300 K. The $\chi(T)$ curve recorded under an external magnetic field H = 3 T after zero-field cooling (ZFC) exhibits a paramagnetic behavior with a weak temperature dependence, indicating the absence of a localized magnetic moment on iron, which is in agreement with the Mössbauer results for LaFe₄P₁₂ (see Ref. 25). Such a nonmagnetic character of iron has been ascribed to the strong covalent bonding with the octahedrally coordinated phosphorous atoms. 13 Electronic structure calculations¹³ of LaFe₄P₁₂ have shown that the highest occupied band consists mainly of the Fe 3d and phosphorous 3s/3p orbitals, which are responsible for the metallic conductivity shown in Fig. 2(b). $\rho(T)$ of our YFe₄P₁₂ sample is almost identical to that reported by Shirontani et al. 14 It is interesting to note that $\rho(T)$ in the normal state follows the Fermi-liquid behavior, viz. $\rho = \rho_0 + AT^2$, at low temperatures. However, the behavior of $\rho(T)$ at higher

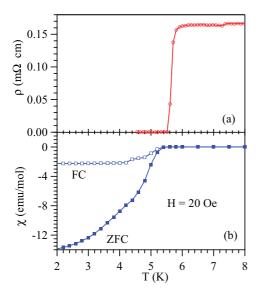


FIG. 3. (Color online) Temperature dependence of (a) resistivity $\rho(T)$ and (b) magnetic susceptibility $\chi(T)$ measured under H=20 Oe after ZFC and FC below 8 K for YFe₄P₁₂. The zero resistivity and diamagnetic signal are observed below 5.5 K.

temperatures resembles the feature of resistivity saturation found in Nb₃Sb.²⁶ We have calculated the Kadowaki-Woods ratio A/γ^2 on the basis of the power-law fitting to $\rho(T)$ and the γ from the specific-heat measurement; ¹⁴ A/ γ^2 = 7.5 × 10⁻⁶ $\mu\Omega$ ·cm·mol²·K²/(mJ)² is close to the universal value of $10^{-5} \mu\Omega \cdot \text{cm} \cdot \text{mol}^2 \cdot \text{K}^2/(\text{mJ})^2$ for most heavy Fermion compounds.²⁷ Instead of the Mott diffusive formula $S(T) \propto$ T for metals, S(T) in Fig. 2(c) displays clear slope changes with decreasing temperature. These observations indicate that the electronic structure near the Fermi level exhibits a subtle evolution as a function of temperature. Although the structural analysis indicated a relatively weak bonding of Y to the (FeP₃)₄ cage, the relatively high thermal conductivity in Fig. 2(d) rules out the possibility of a rattling motion found in some skutterudites. After subtracting the electronic contribution $\kappa_e = \mathrm{LT}/\rho$ according to the Widemann-Franz law, where $L = 2.44 \times 10^{-8} \text{ W} \cdot \Omega \cdot \text{K}^{-2}$, it is clear that the lattice part dominates the heat transfer with a room-temperature value of $\sim 8 \text{ W} \cdot \text{m}^{-1} \cdot \text{K}^{-1}$.

Now we turn to the superconductivity of YFe₄P₁₂ and the pressure effect on T_c . The ambient-pressure $\rho(T)$ data in Fig. 3(a) shows that the YFe₄P₁₂ sample reaches zero resistivity below 5.5 K, where the Meissner signal in $\chi(T)$ appears [see Fig. 3(b)]. We first monitored the pressure dependence of the superconducting transition temperature T_c of YFe₄P₁₂ by measuring its dc magnetization M(T) under various quasihydrostatic pressures up to 1.22 GPa with a miniature BeCu piston-cylinder cell fit into a SQUID magnetometer. The high-pressure M(T) data are shown in the main panel of Fig. 4. As can be seen, with increasing pressure T_c of YFe₄P₁₂ increases while T_c of Sn as a pressure manometer decreases accordingly. We defined T_c as the crossing point of two extrapolated straight lines on the M(T) curve above and below T_c . As shown in the inset of Fig. 4, T_c of YFe₄P₁₂ increases linearly with a coefficient $dT_c/dP = +1.0$ K/GPa, which is larger than that of +0.72 K/GPa for LaFe₄P₁₂ (see Ref. 9). YFe₄P₁₂

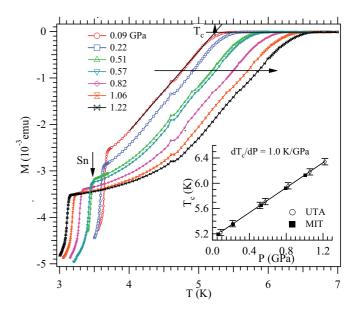


FIG. 4. (Color online) Temperature dependence of magnetization M(T) of YFe₄P₁₂ and Sn used as pressure manometer under various quasihydrostatic pressures up to 1.22 GPa measured with a piston-cylinder device inside the SQUID magnetometer. Inset shows the pressure dependence of T_c .

thus becomes the second filled skutterudite superconductor exhibiting a positive pressure coefficient dT_c/dP , as shown in Table I. In order to clarify whether the pressure dependence of T_c is sample dependent, we have measured the M(T) under pressure on samples from different institutes, the University of Texas at Austin (UTA) and the Muroran Institute of Technology (MIT). As shown in the inset of Fig. 4, the two samples have a nearly identical T_c and its pressure coefficient.

Such a large pressure coefficient of T_c motivated us to check how T_c changes in an extended pressure range. For this purpose, we measured the resistivity $\rho(T)$ of a YFe₄P₁₂ sample prepared at UTA from 4.2 to 300 K under various quasihydrostatic pressures up to 8 GPa with a cubic anvil apparatus. The $\rho(T)$ data are plotted in the main panel of Fig. 5. We defined $T_c = (T_c^{\text{onset}} + T_c^{\text{zero}})/2$ as the middle point between the onset temperature of superconductivity, T_c^{onset} , and the zero-resistivity temperature, T_c^{zero} , while the error bar of T_c represents the transition width $\Delta T_c = (T_c^{\text{onset}} - T_c^{\text{zero}})/2$. The pressure dependence of T_c is shown in the inset of Fig. 5. It should be emphasized that the superconductivity transition remains sharp up to 8 GPa (see the inset of Fig. 5), which indicates a good hydrostatic pressure condition during the measurement. With increasing pressure, T_c increases almost linearly from 5.6 K at ambient pressure to 8.3 K at 5 GPa with a positive slope $dT_c/dP = +0.53(2)$ K/GPa, and then T_c starts to deviate from the line and reaches 9.3 K at 8 GPa. It looks as though the T_c of YFe₄P₁₂ will saturate at higher pressures.

In order to check if T_c will indeed follow a dome-shape $T_c(P)$ curve as found in cuprates, we have performed the measurement of resistance R(T) of YFe₄P₁₂ with a DAC. Although no zero resistance can be observed in this case due to the nonhydrostatic pressure conditions by using a solid PTM, R(T) exhibits a clear drop at the superconducting transition, as

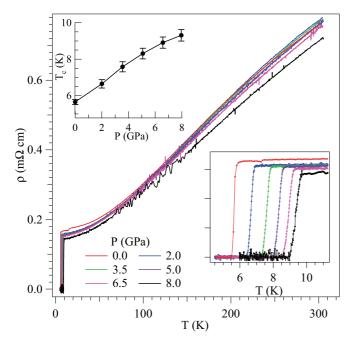


FIG. 5. (Color online) Temperature dependence of resistivity $\rho(T)$ of YFe₄P₁₂ under various quasihydrostatic pressures up to 8 GPa measured with a cubic anvil apparatus. Insets show the pressure dependence of T_c and a zoom-in plot of $\rho(T)$ near T_c .

shown in Fig. 6. T_c of YFe₄P₁₂ first increases with increasing pressure, which is consistent with the above results; then, T_c decreases gradually with further increasing pressure. It should be noted that the pressures inside the DAC were measured at room temperature, which may be different from the actual pressure at T < 10 K. This factor makes the quantitative comparison of the pressure effect on T_c in Figs. 5 and 6 impossible, but the results in Fig. 6 indeed tell us that the T_c of YFe₄P₁₂ undergoes a maximum for P > 8 GPa. Therefore, our present high-pressure studies on YFe₄P₁₂ show that its superconducting transition temperature T_c is first enhanced

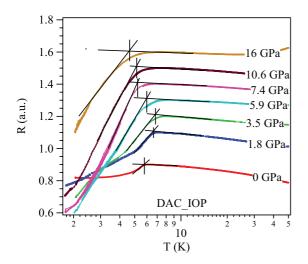


FIG. 6. (Color online) Temperature dependence of resistance R(T) of YFe₄P₁₂ up to 16 GPa measured with a diamond anvil cell. The pressures were measured at room temperature and are expected to be different from the actual value at low temperatures T < 10 K.

with the application of external pressure at least up to 8 GPa, above which T_c is suppressed by pressure, as observed in other filled skutterudite superconductors shown in Table I. A similar trend of T_c versus pressure has also been observed in the LaFe₄P₁₂ (see Ref. 28). We now discuss the possible origin for the positive pressure effect on T_c of RFe₄P₁₂ (R = La, Y) in a broad pressure range.

In the model by DeLong and Meisner, a positive dT_c/dP in LaFe₄P₁₂ has been related to a $dT_c/dP > 0$ in the La metal. Since a $dT_c/dP > 0$ has been observed in the Y metal, ¹⁵ our observation on YFe₄P₁₂ seems to be in line with their argument. A closer inspection of the characteristics of crystal and electronic structures of RFe₄P₁₂, however, raises questions about whether the argument is applicable to YFe₄P₁₂. (1) Y metal is not a superconductor at ambient pressure, and its T_c remains below 4 K for P = 30 GPa. (2) The structural refinements revealed no compression on the filling Y atoms within the (FeP₃)₄ cages. (3) The pressure coefficient of YFe₄ P_{12} is even larger than that of LaFe₄ P_{12} . (4) In contrast with the cases of pure La and Y metal in which the positive dT_c/dP has been ascribed to the increased DOS of 4f (La) or 4d (Y) bands near the Fermi level, ^{29,30} the electronicstructure calculations¹³ for LaFe₄P₁₂ and other rare-earth filled skutterudites³¹ have shown that the contribution from the Rto the DOS near the Fermi level is negligible. This is further confirmed by our band-structure calculations shown below. Taking these factors into account, the atomic properties of filling atoms should not play a major role for the positive dT_c/dP observed in RFe₄P₁₂ (R = La, Y). However, it is obvious that the nonmagnetic character of the rare earth of La and Y is essential to make RFe₄P₁₂ superconductive. The fact that both LaFe₄P₁₂ and YFe₄P₁₂ exhibit a positive dT_c/dP raises another question: Are the Fe-based filled skutterudite superconductors unique with $dT_c/dP > 0$? If so, why? In order to answer these questions satisfactorily, a comprehensive high-pressure study on filled skutterudite superconductors shown in Table I is required and is beyond the scope of the present study.

A positive dT_c/dP of YFe₄P₁₂ is clearly correlated to the pressure-induced change of physical properties in the normal state. Unlike the measurements made with a self-clamp device, the pressure remains constant during the measurement of $\rho(T)$ on cooling down and warming up with the cubic anvil apparatus. Therefore, the $\rho(T)$ data in Fig. 5 contain more useful information for us to extract. The saturation of $\rho(T)$ at high temperatures reflects a relatively strong electron-phonon interaction. As shown in Fig. 5, pressure makes the feature of the resistivity saturation more pronounced, especially in the $\rho(T)$ under 8 GPa. Following the lead that pressure increases the electron-phonon coupling λ , we can interpret the enhancement of T_c under pressure by the Allen-Dynes equation $T_c \sim \lambda^{1/2}$ (see Ref. 32). More interestingly, we have found the parameters in the power-law fitting to the $\rho(T)$ at low temperatures evolves obviously under pressure. As shown in Fig. 7, the residual resistivity ρ_0 changes very little over the pressure range to 8 GPa, which indicates that the grain boundary scattering remains quite small in this highly consolidated high-pressure product. A dramatic increase of A and a reduction of n from two under pressure in $\rho = \rho_0 + AT^n$ are opposite to what we have normally seen in systems at the

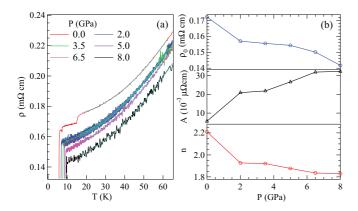


FIG. 7. (Color online) (a) A zoom-in plot of $\rho(T)$ at low temperatures and fitting to a power law $\rho = \rho_0 + AT^n$ from 15–65 K; (b) the pressure dependence of parameters in the fitting to the power law.

crossover from localized to itinerant electronic behavior, for example in PrNiO₃ (see Ref. 33). These changes signal an increased mass enhancement under pressure.

In case the electron-phonon coupling λ in YFe₄P₁₂ falls in a range of 0.45–0.50 (see Refs. 25,34, and 35), T_c can be described quantitatively by the McMillan equation:^{8,36}

$$T_c \approx \frac{\langle \omega \rangle}{1.20} \exp\left[-\frac{1.04(1+\lambda)}{\lambda - \mu^*(1+0.62\lambda)}\right],$$
 (1)

where $\langle \omega \rangle$ is an average phonon frequency, and μ^* is the Coulomb repulsion that is usually set to 0.1. The e-p coupling parameter is further defined as $\lambda \equiv N(E_f)\langle I^2 \rangle/M\langle \omega^2 \rangle$, where $N(E_f)$ is the DOS at Fermi level, $\langle I^2 \rangle$ is the average squared electronic matrix element, M is the molecular mass, and $\langle \omega^2 \rangle$ is the average squared phonon frequency. By taking the logarithmic volume derivative of T_c in Eq. (1), we can obtain the simple relation:

$$-B\frac{d\ln T_c}{dP} = -\gamma + \Delta \left(\frac{d\ln \eta}{d\ln V} + 2\gamma\right),\tag{2}$$

where B is the bulk modulus, $\gamma \equiv -d\ln\langle\omega\rangle/d\ln V$ is the Grüneisen parameter, $\eta \equiv N(E_f)\langle I^2 \rangle$ is the H-p that can be calculated directly by band-structure theory, and $\Delta \equiv 1.04\lambda(1 + 0.38\mu^*)[\lambda - \mu^*(1 + 0.62\lambda)]^{-2}$. Since $\gamma(>0)$ is usually small relative to the second term on the right side of Eq. (2), the sign of the pressure derivative dT_c/dP is determined by the relative magnitude of the two terms inside the bracket. As a well-behaved parameter under pressure, the H-p η can be calculated theoretically. ^{36,37} For simple s, p-metal superconductors, $d\ln\eta/d\ln V \approx -1$. Since Δ is always positive and $2\gamma \approx +3$ to +5, Eq. (2) can explain why most simple s, p-metal superconductors, e.g., Sn and Pb, exhibit a negative dT_c/dP . On the other hand, for transition-metal superconductors, the electrons taking part in the superconductivity have a predominantly d character, which often leads to a higher value of $N(E_f)$. In this case, theoretical calculations have pointed out that a larger $d \ln \eta / d \ln V \approx$ $-3 \sim -4$ is more appropriate.³⁷ When the $|d \ln \eta/d \ln V|$ becomes larger than 2γ , T_c is expected to increase with pressure, e.g., vanadium. 38 Therefore, a large enhancement of T_c with pressure for RFe_4P_{12} (R = La and Y) signals a $|d \ln \eta/d \ln V| > 2\gamma$, and a relatively large $|d \ln \eta/d \ln V|$ indicated that the $N(E_f)$ may undergo a dramatic increase under pressure. As shown below, this scenario is indeed confirmed by our band-structure calculations and the subsequent evaluation of H-p under 0 and 8 GPa for YFe₄P₁₂.

We performed a full-potential linearized augmented-planewave (FLAPW) calculation on YFe₄P₁₂ and applied the rigid-muffin-tin (RMT) theory of Gaspari and Gyorffy³⁹ to determine the value of (H-p) η given by the expression for atom A:

$$\eta = \sum_{A} \eta_{A} = N(E_{f}) \sum_{A} n_{A} \langle I_{A}^{2} \rangle
= \sum_{A} \sum_{l} 2(l+1) M_{(A,(l,l+1))}^{2} \frac{f_{l}^{A}}{2l+1} \frac{f_{l+1}^{A}}{2l+3},$$
(3)

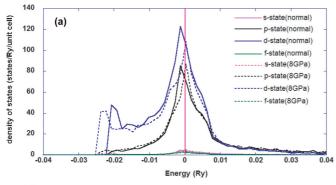
where n_A is the number of type A atom in the unit cell, $f_l^A = N_l^A(E_f)/N(E_f)$ is a relative partial state density for angular momentum l and type A atom, and $N(E_f)$ is the total DOS at the E_f , $N_l^A(E_f)$ are the l components of the DOS inside the muffin-tin (MT) spheres for type A atom, and $N(E_f) = \sum_{A,l} n_A N_l^A(E_f)$. $M_{(A,(l,l+1))}$ is the electron-phonon matrix element, which is given in RMT by the expression 40 in terms of the logarithmic derivatives $D_l(E_f)$ evaluated at E_f and at the MT radius (S) for type A atom:

$$M_{(A,(l,l+1))} = -\phi_l(E_f)\phi_{l+1}(E_f)[\{D_l(E_f) - l\} \times \{D_{l+1}(E_f) + l + 2\} + \{E_f - V(S)\}S^2], \quad (4)$$

where $\phi_l(E_f)$ is the partial wave amplitude at E_f , and V(S) is the one-electron potential at S.

The necessary input to Eqs. (3) and (4) was generated from FLAPW calculations. In the calculations, 35 sampling k-points in the irreducible Brillouin zone (IBZ) are used for potential convergence, and 195 sampling k-points in IBZ are used for final band structures. About 5400 LAPW basis functions are used to obtain eigenvalues for each k-point. These were performed at the experimental crystal structures fixing the position of the pnictogen group, with respect to the transition metal, to u = 0.1472a and v = 0.3519a. The MT sphere radii were set as 0.1907a for Y, 0.1444a for both Fe and P. The lattice parameter is a = 7.7913 Å for ambient pressure and a = 7.66995 Å for 8 GPa. For comparison, the FLAPW calculations were also performed for YRu₄P₁₂ in which the lattice parameter is a = 8.0298 Å at ambient pressure and a = 7.90474 Å at 8 GPa. The present calculations of the band structure and the Fermi surface at ambient pressure are in good agreement with previous literature. 42,43

In the case of YFe₄P₁₂, two conduction bands (the 47th and 48th) cross the Fermi level, and the 48th band only crosses the Fermi level for YRu₄P₁₂. For YFe₄P₁₂, the 47th Fermi surface is sufficiently small compared to the 48th one. The $N(E_f)$ s of both the 47th and 48th bands are 10.57 (8.13) states/Ry and 253.33 (287.47) states/Ry for ambient pressure (8 GPa), respectively. Therefore, only the 48th band is presented in the evaluation of H-p. The angular momentum components $N_l(E_f) = \sum_A n_A N_l^A(E_f)$ of the DOS in the 48th band are shown in Figs. 8(a) and 8(b) for YFe₄P₁₂ and YRu₄P₁₂, respectively. The dominant components of $N_l(E_f)$ are those from both p states $N_p(E_f)$ and d states $N_d(E_f)$ for both



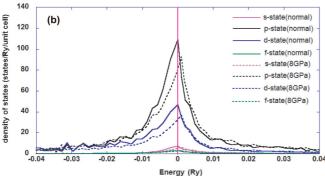


FIG. 8. (Color online) The angular momentum components of the density of states in the 48th band for normal pressure (solid line) and 8 GPa (broken line) in the vicinity of the Fermi energy $E_f=0.0$ Ry: (a) YFe₄P₁₂, (b) YRu₄P₁₂.

 YFe_4P_{12} and YRu_4P_{12} . As shown in Table IV for YFe_4P_{12} , the $N_p(E_f)$ (mainly due to P 3p electrons) and the $N_d(E_f)$ (mainly due to Fe 3d electrons) increase under pressure, respectively. In contrast, both the $N_p(E_f)$ (mainly due to P 3p electrons) and the $N_d(E_f)$ (mainly due to Ru 4d electrons) decrease under pressure for YRu₄P₁₂. The calculated values of η for YFe₄P₁₂ are 3.68 eV/Å² and 5.16 eV/Å² at ambient pressure and 8 GPa, respectively. Note that the value of the η increases by about 40% under 8 GPa. In addition, the Fe contribution to η is more than 70% for both ambient pressure and 8 GPa, and the dominant contributions come from p-d and d-f scattering. On the other hand, the η of YRu₄P₁₂ decreases from the 4.88 eV/ $Å^2$ at ambient pressure to the 4.74 eV/ $Å^2$ at 8 GPa. In this case, the p contribution to η is about 40%, and p-d and d-f scattering are dominant. It is noted that the value of η for niobium, which is a typical transitionmetal superconductor, is in the range $5.4 \sim 7.6 \text{ eV/Å}^2$ (see Ref. 44) and is comparable to the value η obtained here. We can thus conclude that the large variation of the η under pressure for YFe₄P₁₂ is responsible for the observed increase of T_c with pressure. The main contributions to the enhancement of η are due to the increase of both $N_p(E_f)$ and

TABLE IV. The atom-resolved and the total H-p in eV/Å 2 for YFe $_4$ P $_{12}$ and YRu $_4$ P $_{12}$ at ambient pressure and 8 GPa. Angular momentum components of the density of states at E_f in units of states/(Ry unit cell).

Sample	P (GPa)	$N(E_f)_p$	$N(E_f)_d$	$\eta_{ m Y}$	$\eta_{ m Fe/Ru}$	$\eta_{ m P}$	η
YFe ₄ P ₁₂	0	70.16	104.36	0.06	2.80	0.82	3.68
	8	86.57	108.51	0.08	4.02	1.06	5.16
YRu_4P_{12}	0	109.17	46.86	0.07	3.35	1.46	4.88
	8	90.33	38.27	0.08	3.34	1.32	4.74

 $N_d(E_f)$ as shown in Table IV. Although there is no high-pressure study on the variation of T_c at present for YRu₄P₁₂, a small negative slope dT_c/dP expected from the above analysis is consistent with the result of LaRu₄P₁₂.

In summary, we report comprehensive characterizations of filled skutterudite YFe₄P₁₂ synthesized under high pressure. As found in LaFe₄P₁₂, a $dT_c/dP = +1.0$ K/GPa at lower pressures and a $dT_c/dP = +0.53$ K/GPa to 5 GPa have been obtained from the measurements of magnetization and resistivity under quasihydrostatic pressures up to 8 GPa. The detailed structural refinement on YFe_4P_{12} revealed that the pressure effect on T_c of the filled skutterudite should have little to do with that of the corresponding R metals. From the analysis of transport property in the normal state of YFe₄P₁₂, pressure appears to increase the mass enhancement and to strengthen the electron-phonon interaction. The observed large $dT_c/dP > 0$ of YFe₄P₁₂ was further explained by our band-structure calculations that show an enhancement of both $N(E_f)$ and the H-p under pressure at least up to 8 GPa. On the other hand, similar calculations predict a $dT_c/dP < 0$ for YRu_4P_{12} .

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